

**ADVANCED
POWER
TECHNOLOGY®**

APT2X60D100J 1000V 60A
APT2X61D100J 1000V 60A

DUAL DIE ISOTOP® PACKAGE

ULTRAFAST SOFT RECOVERY DUAL RECTIFIER DIODES

PRODUCT APPLICATIONS	PRODUCT FEATURES	PRODUCT BENEFITS
• Anti-Parallel Diode -Switchmode Power Supply -Inverters • Free Wheeling Diode -Motor Controllers -Converters • Snubber Diode • Uninterruptible Power Supply (UPS) • Induction Heating • High Speed Rectifiers	• Ultrafast Recovery Times • Soft Recovery Characteristics • Popular SOT-227 Package • Low Forward Voltage • High Blocking Voltage • Low Leakage Current	• Low Losses • Low Noise Switching • Cooler Operation • Higher Reliability Systems • Increased System Power Density

MAXIMUM RATINGS

All Ratings: $T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT2X60/2X61D100J	UNIT
V_R	Maximum D.C. Reverse Voltage	1000	Volts
V_{RRM}	Maximum Peak Repetitive Reverse Voltage		
V_{RWM}	Maximum Working Peak Reverse Voltage		
$I_F(AV)$	Maximum Average Forward Current ($T_C = 50^\circ\text{C}$, Duty Cycle = 0.5)	60	Amps
$I_F(RMS)$	RMS Forward Current	100	
I_{FSM}	Non-Repetitive Forward Surge Current ($T_J = 45^\circ\text{C}$, 8.3ms)	540	
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_L	Lead Temperature: 0.063" from Case for 10 Sec.	300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
V_F	Maximum Forward Voltage	$I_F = 60\text{A}$		2.5	Volts
		$I_F = 120\text{A}$		2.1	
		$I_F = 60\text{A}, T_J = 150^\circ\text{C}$		2.0	
I_{RM}	Maximum Reverse Leakage Current	$V_R = V_R$ Rated		250	μA
		$V_R = V_R$ Rated, $T_J = 125^\circ\text{C}$		500	
C_T	Junction Capacitance, $V_R = 200\text{V}$		65		pF
L_S	Series Inductance (Lead to Lead 5mm from Base)		10		nH

USA

405 S.W. Columbia Street

EUROPE

Avenue J.F. Kennedy Bât B4 Parc Cadéra Nord

APT Website - <http://www.advancedpower.com>

Bend, Oregon 97702-1035

F-33700 Merignac - France

Phone: (541) 382-8028

Phone: (33) 5 57 92 15 15

FAX: (541) 388-0364

FAX: (33) 5 56 47 97 61

DYNAMIC CHARACTERISTICS

APT2X60/2X61D100J

Symbol	Characteristic	MIN	TYP	MAX	UNIT
t_{rr1}	Reverse Recovery Time, $I_F = 1.0A$, $di_F/dt = -15A/\mu s$, $V_R = 30V$, $T_J = 25^\circ C$		70	85	ns
t_{rr2}	Reverse Recovery Time		70		
t_{rr3}	$I_F = 60A$, $di_F/dt = -480A/\mu s$, $V_R = 540V$		130		
t_{fr1}	Forward Recovery Time		200		
t_{fr2}	$I_F = 60A$, $di_F/dt = 480A/\mu s$, $V_R = 540V$		200		
I_{RRM1}	Reverse Recovery Current		14	26	Amps
I_{RRM2}	$I_F = 60A$, $di_F/dt = -480A/\mu s$, $V_R = 540V$		26	36	
Q_{rr1}	Recovery Charge		500		nC
Q_{rr2}	$I_F = 60A$, $di_F/dt = -480A/\mu s$, $V_R = 540V$		1700		
V_{fr1}	Forward Recovery Voltage		15.5		Volts
V_{fr2}	$I_F = 60A$, $di_F/dt = 480A/\mu s$, $V_R = 540V$		15.5		
diM/dt	Rate of Fall of Recovery Current		900		A/ μs
	$I_F = 60A$, $di_F/dt = -480A/\mu s$, $V_R = 540V$ (See Figure 10)		600		

THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			0.66	$^\circ C/W$
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance			20	
$V_{Isolation}$	RMS Voltage (50-60 Hz Sinusoidal Waveform from Terminals to Mounting Base for 1 Min.)	2500			Volts
W_T	Package Weight		1.03		oz
			29.2		gm
Torque	Maximum Torque (Mounting = 8-32 or 4mm Machine and Terminals = 4mm Machine)			13.6	lb•in
				1.5	N•m

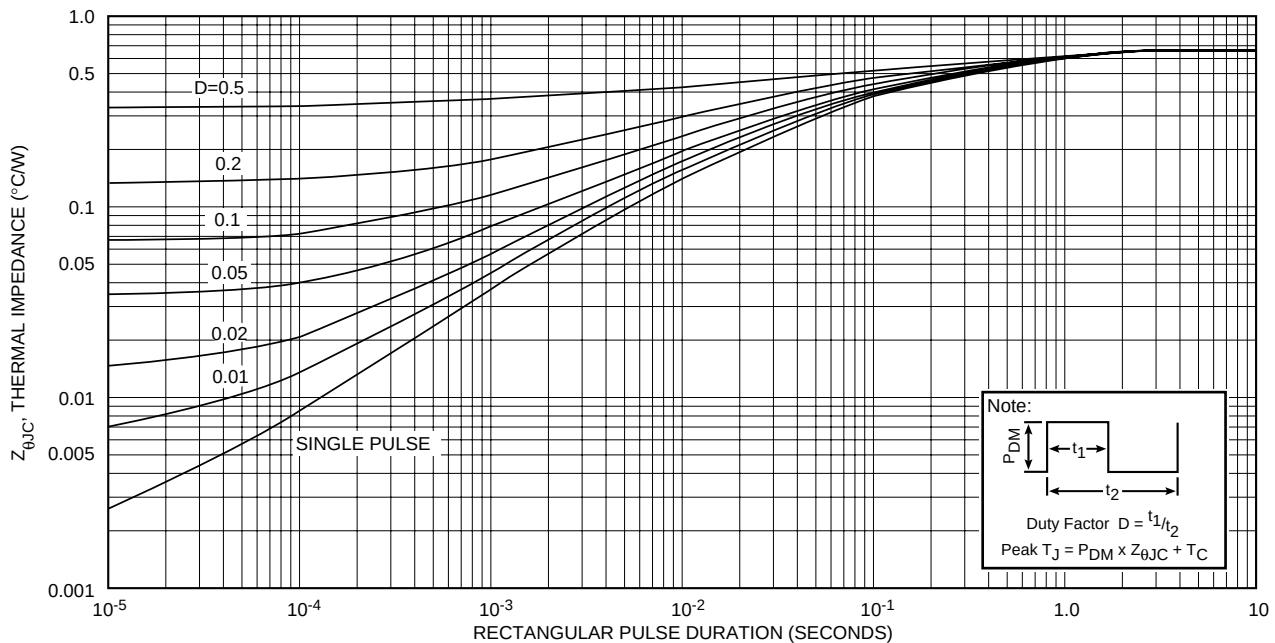


FIGURE 1, MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs PULSE DURATION

APT2X60/2X61D100J

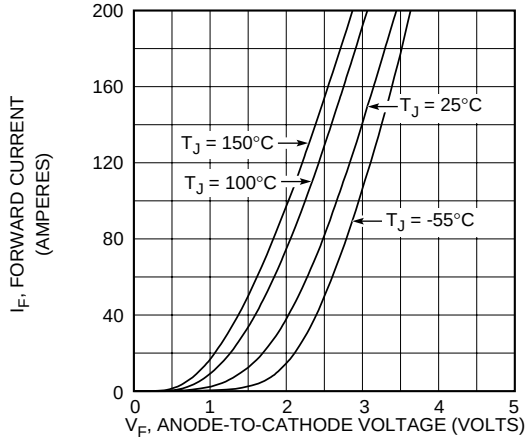


Figure 2, Forward Voltage Drop vs Forward Current

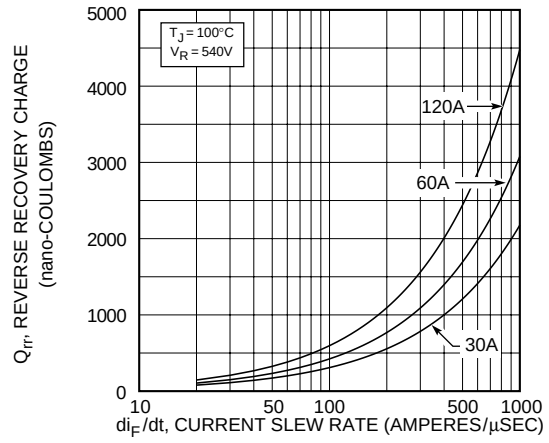


Figure 3, Reverse Recovery Charge vs Current Slew Rate

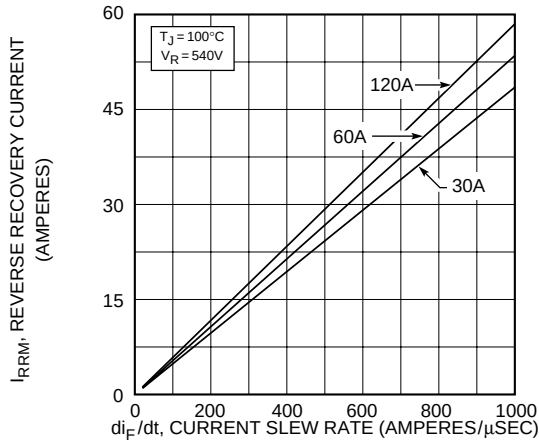


Figure 4, Reverse Recovery Current vs Current Slew Rate

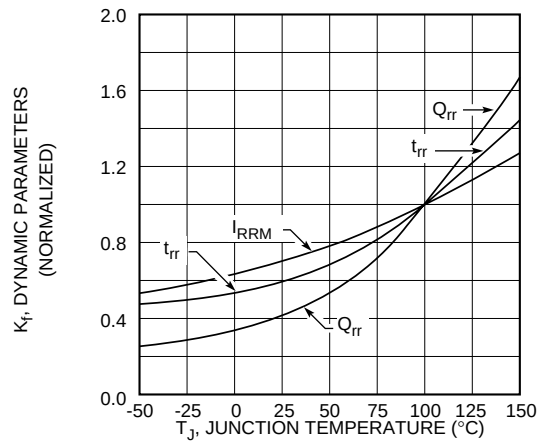


Figure 5, Dynamic Parameters vs Junction Temperature

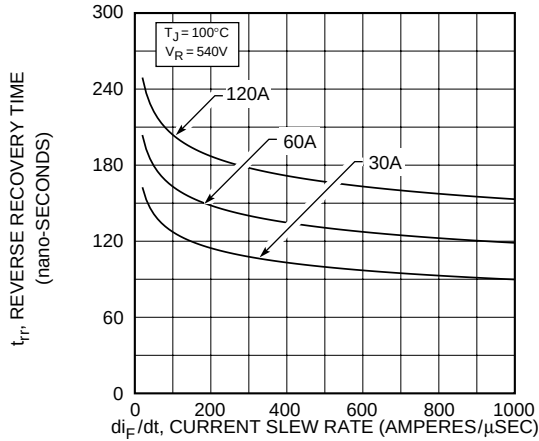


Figure 6, Reverse Recovery Time vs Current Slew Rate

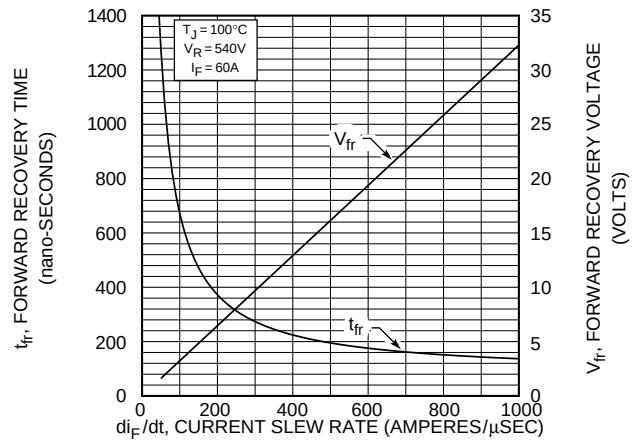


Figure 7, Forward Recovery Voltage/Time vs Current Slew Rate

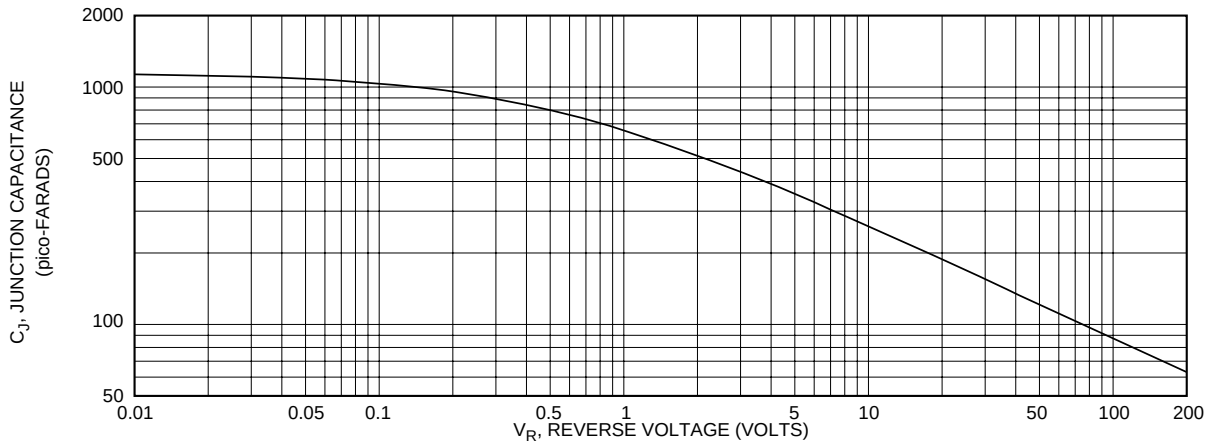


Figure 8, Junction Capacitance vs Reverse Voltage

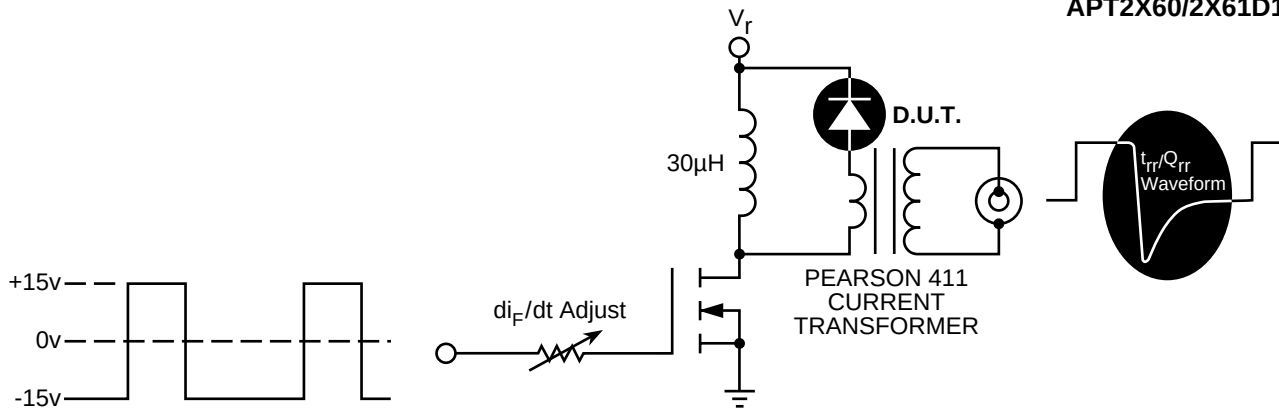


Figure 9, Diode Reverse Recovery Test Circuit and Waveforms

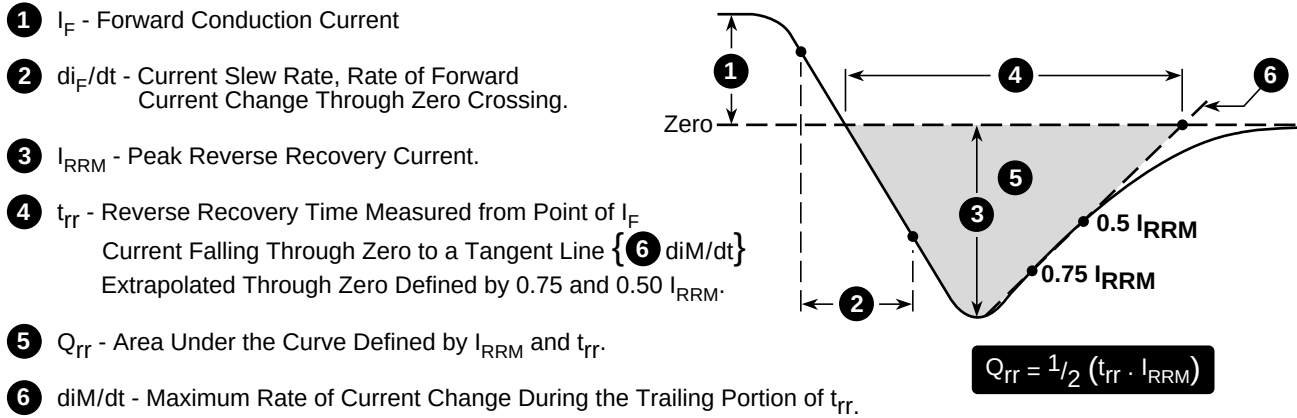
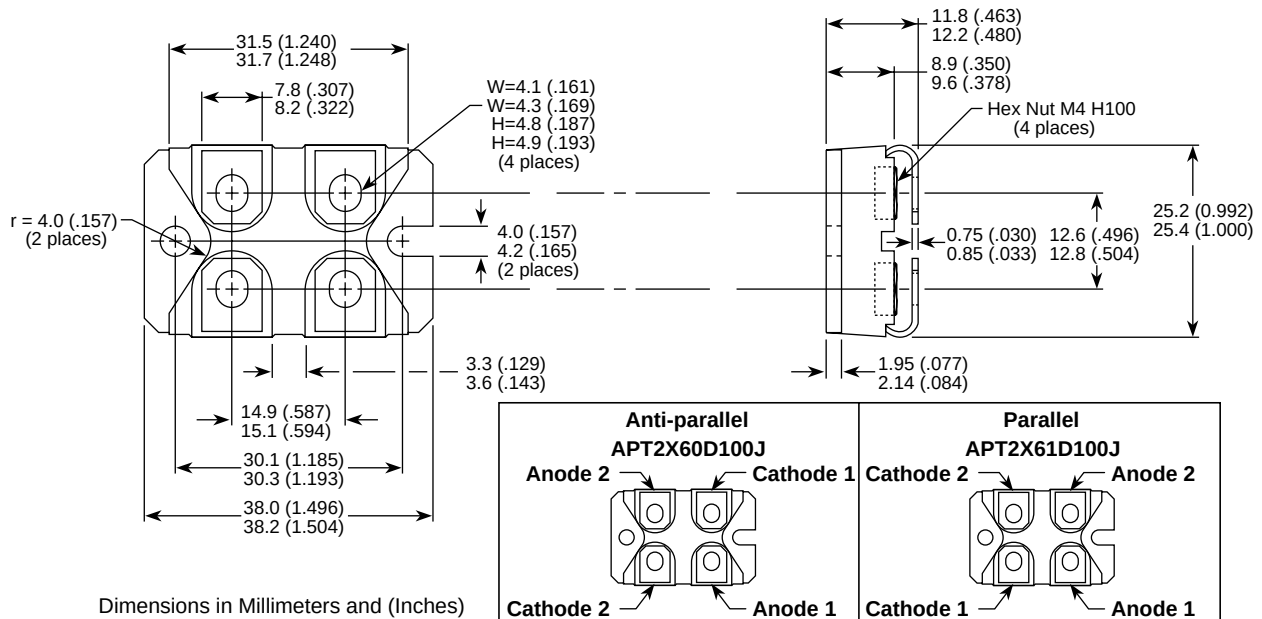


Figure 10, Diode Reverse Recovery Waveform and Definitions

APT Reserves the right to change, without notice, the specifications and information contained herein.

SOT-227 Package Outline



Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9